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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**In re Application of**

Noboru Ichinose, et al.

Serial No.: 10/567,369**Group Art Unit:** 2814**Filed:** May 15, 2006**Examiner:** Sarah Kate Salerno**For:** SEMICONDUCTOR LAYER WITH A Ga_2O_3 SYSTEMHonorable Commissioner of Patents
Alexandria, VA 22313 - 1450
BOX AF**AMENDMENT UNDER 37 C.F.R. §1.116**

Sir:

In response to the Office Action dated October 22, 2010, please amend the above-identified application as follows:

INTRODUCTORY COMMENTS

Claims 1, 4, 6, 9-13, 15, and 21 are all the claims presently pending in the application.

Amendments to the claims begin on page 2 of this paper. No new matter is added.

Remarks begin at page 4 of this paper.